

(2) 09/940011
(52) ((anti adj fuse antifuse)0
(0) 10/820415
(4845) (anti adj fuse antifuse)
(33601) (magnetoresist4 magneto adj resist4 TMR) (mtj magnetic adj tunnel adj ju
(3082) tunnel\$4 near (magnetoresist4 magneto adj resist4 TMR) (mtj magnetic a
(1308408) (((ferr?magnetic ferr? adj magnetic) ((magnetic) (magnetoresist4 m
(87) ((anti adj fuse antifuse)0
(1838472) @ad > 20020322
(21978117) @ad < 20020322
(47) ((anti adj fuse antifuse)0
(1284826) magnetic
(412) ((anti adj fuse antifuse)0
(2548) 8.ab. 8.cfm.
(117) (((anti adj fuse antifuse)0
(495805) angstrom nm
(38) (((anti adj fuse antifuse)0
(28) (((anti adj fuse antifuse)0
(151611) tunnel\$4
(105000) (aluminum adj oxide "al.sub.20.sub.3")
(727) tunnel\$4 with (aluminum adj oxide "al.sub.20.sub.3")
(5287) (tunnel\$4 (aluminum adj oxide "al.sub.20.sub.3")) near0 (angstrom nm)
(277) (tunnel\$4 with (aluminum adj oxide "al.sub.20.sub.3")
(102835) (barrier conformal) near2 (diffusion layer liner)
(8938) (anti adj (ferr?magnetic ferr? adj magnetic magnetic) antiferr?magnetic a
(1495479) pin \$4

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Default operator:	GR		
<input type="checkbox"/> Plurals			
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(((anti adj fuse antifuse)) with (((ferr?magnetic ferr? adj magnetic) ((magnetic) (magnetoresist4 magneto adj resist4)) TMR (mtj magnetic adj tunnel adj junction))) MRAM) and (@ad < 20020322)			

Sept. 2004

#	1	Inventor	Document#	Issue	P	Title	Current	Current XM	Retrieval	S	C	P	2	3	Image	Doc.	P
1		Tran, Lung T.	US 6473337	20021	1	Memory device having memory cells with ma	365/173	365/158								US 6473337	
2		Sharma, Man	US 6483734	20021	1	Memory device having memory cells capable	365/87	365/100								US 6483734	
3		Tran, Lung T.	US 2003017	20030	1	Memory device array having a pair of magne	365/100									US 2003017	
4		Eldredge, Ken	US 2003013	20030	1	Self-healing MRAM	365/200									US 2003013	
5		Tran, Lung T.	US 2003008	20030	7	Test array and method for testing memory ar	365/201									US 2003008	
6		Tran, Lung T.	US 6778421	20040	1	Memory device array having a pair of magne	365/105	365/100								US 6778421	
7		Fricke, Peter	US 6717215	20040	1	Memory structures	257/347	257/301								US 6717215	
8		Eldredge, Ken	US 6643195	20031	1	Self-healing MRAM	365/200	365/230.01								US 6643195	
9		Tran, Lung T.	US 6639859	20031	7	Test array and method for testing memory ar	365/201	365/214								US 6639859	
10		Miller, Paul J.	US 6613979	20030	2	Electrical circuit suspension system	174/52	174/254								US 6613979	